

#### 40V N-Channel Enhancement Mode MOSFET

Current

#### Features

Voltage

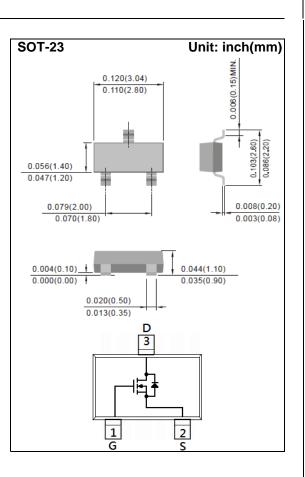
- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@4.3A < 42m\Omega$
- $R_{DS(ON)}, V_{GS}@4.5V, I_D@3.9A < 51m\Omega$
- Advanced Trench Process Technology

40 V

- Specially Designed for switch Load, PWM applications, and solid-state relays relay
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams



#### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

4.3A

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	40	V	
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 20		
Continuous Drain Current		lь	4.3	A	
Pulsed Drain Current (Note 4)		ldм	17.2		
Power Dissipation	T <sub>a</sub> =25°C	PD	1.25	W	
	Derate above 25°C		10	mW/∘C	
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~150	٥C	
Typical Thermal Resistance - Junction to Ambient (Note 3)		R <sub>θJA</sub>	100	°C/W	



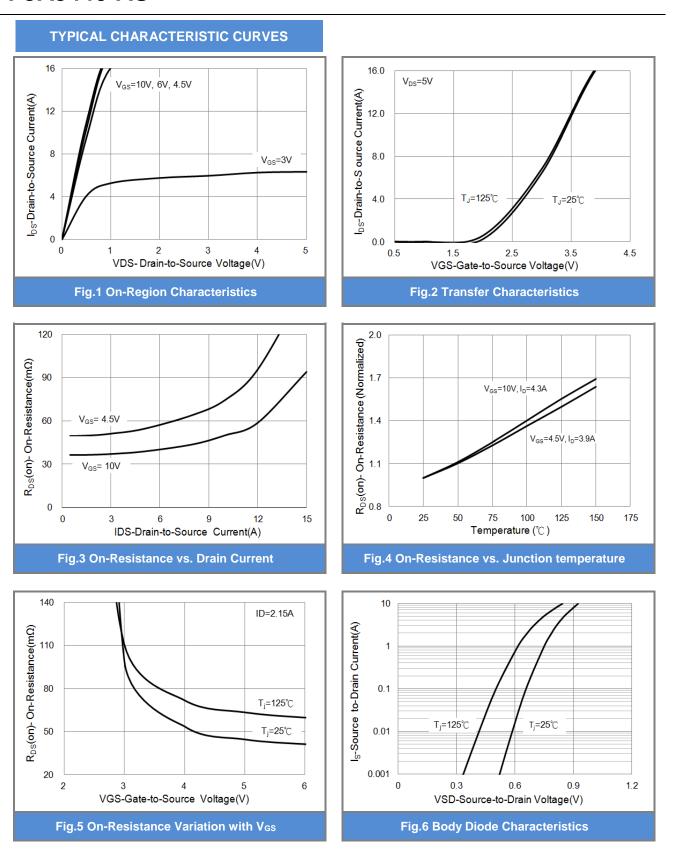
#### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	Vgs=0V, Id=250uA	40	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1.0	1.5	2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =4.3A	- 35 42		42	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =3.9A -		44	51	
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =40V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	lgss	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 5)			_			
Total Gate Charge	Qg		-	4.8	-	nC
Gate-Source Charge	Qgs	$V_{DS}=20V, I_{D}=4.3A,$	-	1.4	-	
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =4.5V <sup>(Note 1,2)</sup>	-	1.8	-	
Input Capacitance	Ciss		-	410	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V, f=1.0MHZ	-	50	-	
Reverse Transfer Capacitance	Crss	I=1.0IVIHZ	-	30	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	4	-	ns
Turn-On Rise Time	tr	$V_{DD}=20V, I_{D}=3.5A,$	-	30	-	
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}=10V$ ,	-	15	-	
Turn-Off Fall Time	tf	$R_G=1\Omega$ (Note 1,2)	-	8	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					1.0	A
Diode Forward Current	ls			-		
Diode Forward Voltage	V <sub>SD</sub>	Is=1.0A, V <sub>GS</sub> =0V	-	0.78	1.2	V
Reverse Recovery Time	trr	V <sub>GS</sub> =0V, I <sub>S</sub> =3.5A	-	10.2	-	ns
Reverse Recovery Charge	Qrr	dl⊧/ dt=100A/us	-	5.5	-	nC

NOTES :

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.







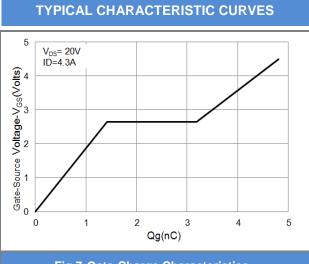
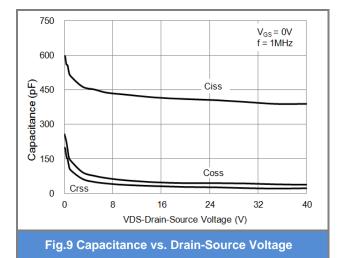
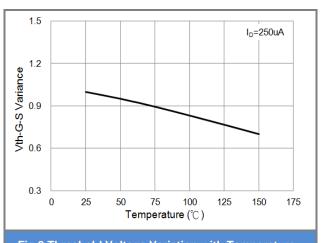
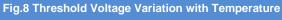


Fig.7 Gate-Charge Characteristics





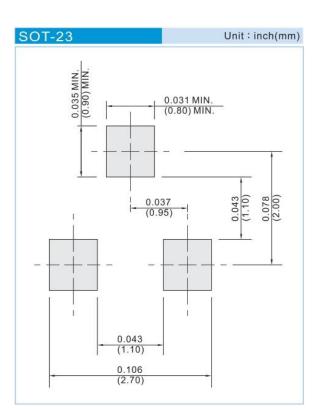




#### **Product and Packing Information**

Part No.	Package Type	Packing Type	Marking	
PJA3440-AU	SOT-23	3K pcs / 7" reel	A40	

### **Mounting Pad Layout**





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